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Serial No. 09/116,138



TI-24953

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

VIA FACSIMILE: (703) 305-3431

(703) 305-3432

Applicants: Anthony et al.

Serial No.: 09/116,138

Filed: 15 July 1998

Art Unit: 2814

Examiner: Bernard Su

For: High Permittivity Silicate Gate Dielectric

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FJONES
8-10-99

AMENDMENT PURSUANT TO 37 C.F.R. § 1.111

**Assistant Commissioner for Patents** Washington, DC 20231

Dear Sir:

As a result of a telephone conversation between the undersigned and Examiner Su on this date, Applicants request that the subject application be amended as follows:

## IN THE CLAIMS

Please cancel Claims 31-35 without prejudice.

## REMARKS

Claims 31-35 of this application are being canceled by this paper as being drawn to a device, while Claims 1-30, drawn to a method, and Claims 36-40, drawn to a product by process, remain in the application.

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Prompt examination of this application in view of the election of Claims 1-30 and 36-40 is respectfully requested.

Respectfully submitted,

Christophen L. Maginniss Atterney for Applicants

Reg. No. 30,288

Texas Instruments Incorporated P. O. Box 655474, MS 3999 Dallas, TX 75265 (972) 917-4259

FAX: (972) 917-4418

6 August 1999